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EFS ID:

11807

Application ID:

09681988

Title of Invention:

METHOD OF FABRICATING A

VERTICAL MOS TRANSISTOR

First Named Inventor:

Tai-Ju Chen

Domestic/Foreign Application:

Domestic Application

Filing Date:

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Effective Receipt Date:

2001-07-03

Submission Type:

Utility Patent Filing

Filing Type:

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Confirmation Number:

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Attorney Docket Number:

NAUP0386USA

Digital Certificate Holder:

cn=Winston Hsu, ou=Registered Attorneys, ou=Patent and

Trademark Office, ou=Department of Commerce, o=U.S.

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Certificate Message Digest:

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Total Fees Authorized:

\$750.0

Payment Category:

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Deposit Account Number:

500801

Deposit Account Name:

WINSTON HSU

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TRANSMITTAL FORM



Electronic Version 1.0.2

Stylesheet Version: 1.0

Attorney Docket Number: NAUP0386USA

METHOD OF FABRICATING A VERTICAL MOS TRANSISTOR

First Named Inventor: Tai-Ju Chen

SUBMITTED BY

Name:

Mr. WINSTON HSU

Registration Number:

41,526

Electronic Signature Mark: Winston

Liectronic signature Mark. Willst

Hsu

Date Signed: 20010704

I certify that the use of this system is for OFFICIAL correspondence between patent applicants or their representatives and the USPTO. Fraudulent or other use besides the filing of official correspondence by authorized parties is strictly prohibited, and subject to a fine and/or imprisonment under applicable law.

I, the undersigned, certify that I have viewed a display of document(s) being electronically submitted to the United States Patent and Trademark Office, using either the USPTO provided style sheet or software, and that this is the document(s) I intend for initiation or further prosecution of a patent application noted in the submission. This document(s) will become part of the official electronic record at the USPTO.

Attached Files:

specification

NAUP0386.xml

declaration

NAUP0386DEC1.TIF

declaration

NAUP0386DEC2.TIF

bibd-transmittal

NAUP0386apds.xml

fee-transmittal

NAUP0386fee.xml

Attached Image File(s):

NAUP0386DEC1.TIF

NAUP0386DEC2.TIF

Comments:

Docket No: NAUP0386USA

COMBINED DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare that:

I believe I am the sole (if only one name appears below), or joint (if more than one name appears), original and first inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled:

"METHOD OF FABRICATING A VERTICAL MOS TRANSISTOR"

The specification for the above entitled invention was filed previously
with application serial number:Filing Date:
I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.
I acknowledge the duty to disclose information which is material to the patentability of the invention disclosed in this application in accordance with Title 37, Code of Federa Regulations, Section 1.56 (a). I further acknowledge the duty in any continuation-in-par application to disclose to the Patent and Trademark Office all information known to be material to the patentability of the invention disclosed in this application, as defined in 1.56, which became available to me between the filing date of the prior application and the filing date of this application.
PRIORTY CLAIM
There is no claim of priority
Claim of priority is based on the following:
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POWER OF ATTORNEY

As a named inventor, I hereby appoint the following attorney to prosecute this application and to transact all related business in the Patent and Trademark Office:

> Winston Hsu, Registration Number 41,526 5F, No.389, Fu-Ho Rd., YUNGHO City, Taipei Hsien, Taiwan, R.O.C.

DECLARATION

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued hereon.

Date:	<u> 6-79. 2001</u>	<u> </u>
	Printed Name: Post Office Address: and Residence Citizen of:	Tai-Ju Chen No.32, Lane 572, Wen-Hsien Rd., Tai-Nan City, Taiwan, R.O.C. R.O.C.
Date:	<u> </u>	Vin Theo Lan
	Printed Name: Post Office Address: and Residence	Hua-Chou Tseng No.1, Lane 62, Kuang-Hua St., Hsin-Chu City, Taiwan, R.O.C.
	Citizen of:	R.O.C.

FEE TRANSMITTAL

Electronic Version 1.0.4 Stylesheet Version: 1.0

Patent fees are subject to annual revisions on or about October 1st of each year.

Large Entity

TOTAL FEES AUTHORIZED: \$750

The commissioner is hereby authorized to charge indicated processing and/or publication fees and credit any overpayments to:

Deposit Account Number: 500801

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Charge Any Additional Fee Required Under 37 C.F.R. Sections 1.16 and 1.17.

SUBMITTED BY

Authorized Name:

WINSTON HSU

Electronic Signature Mark:

VAEB-JMXX-8IIL

Date Signed:

20010703

BASIC FILING FEE

Fee Description	Fee Code	Fee Paid
Utility Filing Fee	101	\$ 710

Subtotal For Basic Filing Fee: \$710

EXTRA CLAIM FEES

	Fee Code	Fee	Extra Claims	Fee Paid
Total Claims: 13	103	\$ 18	0	\$ O
Independent Claims: 2	102	\$ 80	0	\$ 0

Subtotal For Extra Claims Fees: \$ 0

ADDITIONAL FEES

Fee Description	Fee Code	Fee Paid
Recording Each Patent Assignment Per Property Fee	581	\$ 40

Subtotal For Additional Fees: \$ 40